NSN 5962-00-434-3133

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View Online at https://aerobasegroup.com/nsn/5962-00-434-3133

| view Offiline at https://aerobasegroup.com/hist//3302-00-434-3133 |
|---|
| Body Outside Diameter: |
| 0.550 inches |
| Body Height: |
| Between 0.050 inches and 0.070 inches |
| Maximum Power Dissipation Rating: |
| 150.0 milliwatts |
| Operating Tempurature Range: |
| -55.0/+125.0 degrees celsius |
| Storage Tempurature Range: |
| -65.0/+150.0 degrees celsius |
| Features Provided: |
| Monolithic and hermetically sealed and w/enable |
| Inclosure Material: |
| Glass and metal |
| Inclosure Configuration: |
| Flat pack |
| Output Logic Form: |
| P-type metal oxide-semiconductor logic |
| Input Circuit Pattern: |
| 3 input |
| Terminal Surface Treatment: |
| Solder |
| Voltage Rating And Type Per Characteristic: |
| 0.3 volts power source |
| Time Rating Per Chacteristic: |
| 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, high to low level |
| output |
| Memory Device Type: |
| Rom |
| Precious Material And Location: |
| Terminal and top and bottom surfaces gold |
| Precious Material: |
| Gold |
| Test Data Document: |
| 13499-351-8095 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc |
| excludes any specification, standard or other document that may be referenced in a basic governing drawing) |
| Terminal Type And Quantity: |
| 22 flat leads |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |

Yes - demil/mli

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